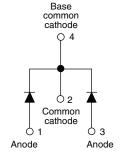


Vishay Semiconductors

COMPLIANT

Schottky Rectifier, 2 x 6 A





D-PAK	(TO-252AA)
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PRODUCT SUMMARY				
Package	D-PAK (TO-252AA)			
I _{F(AV)}	2 x 6 A			
V_{R}	30 V			
V _F at I _F	0.37 V			
I _{RM}	58 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Common cathode			
E _{AS}	10 mJ			

FEATURES

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

DESCRIPTION

The VS-12CWQ03FNPbF surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	12	A			
V_{RRM}		30	V			
I _{FSM}	t _p = 5 µs sine	320	А			
V _F	6 Apk, T _J = 125 °C (per leg)	0.37	V			
T _J	Range	- 55 to 150	°C			

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-12CWQ03FNPbF UNITS						
Maximum DC reverse voltage	V_{R}	30	V			
Maximum working peak reverse voltage	V _{RWM}	30	V			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDI	TEST CONDITIONS		UNITS
Maximum average forward current	per leg		I _{F(AV)} 50 % duty cycle at T _C = 135 °C, rectangular waveform		6	Α
See fig. 5	per device	'F(AV)			12	
Maximum peak one cycle non-repetitive surge current per leg See fig. 7			5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	320	А
		I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	130	
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 2.0 A, L = 5 mH		10	mJ
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		2.0	Α

VS-12CWQ03FNPbF

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Schottky Rectifier, 2 x 6 A



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		6 A	- T _{.1} = 25 °C	0.47	V	
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	12 A	11 = 23 0	0.55		
See fig. 1	VFM (*)	6 A	- T _{.1} = 125 °C	0.37		
		12 A	1J = 125 C	0.49	1	
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	3	mA	
See fig. 2	I 'RM ` '	T _J = 125 °C	VR - Nateu VR	58	IIIA	
Threshold voltage	V _{F(TO)}	T T		0.196	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum	21.66	mΩ		
Typical junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal ran	590	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 r	mm from package body	5.0	nΗ	

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T _J ⁽¹⁾ , T _{Stg}		- 55 to 150	°C	
Maximum thermal resistance,	per leg	D	DC operation	3.0	°C/W	
junction to case	per device	R_{thJC}	See fig. 4	1.5	C/ VV	
Annuavimenta vuoinht				0.3	g	
Approximate weight				0.01	OZ.	
Marking device			Case style D-PAK (similar to TO-252AA)	12CW	Q03FN	

Note

(1)
$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink



Schottky Rectifier, 2 x 6 A

Vishay Semiconductors

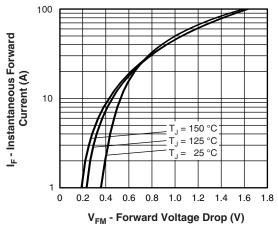


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

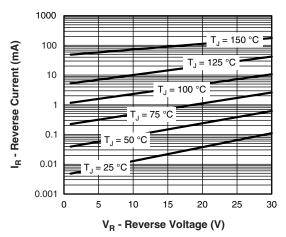


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

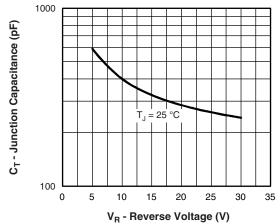


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

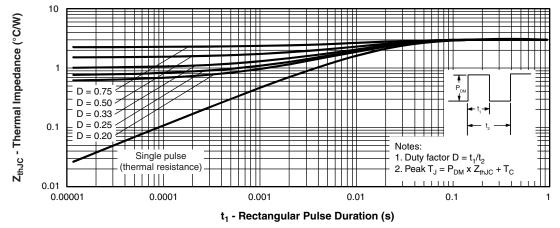


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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Schottky Rectifier, 2 x 6 A



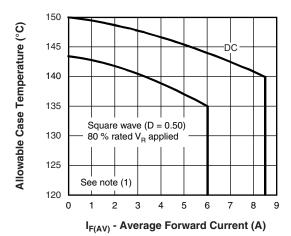


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

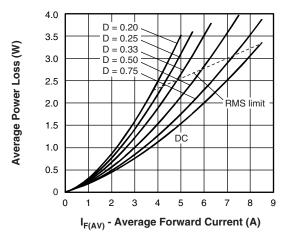


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

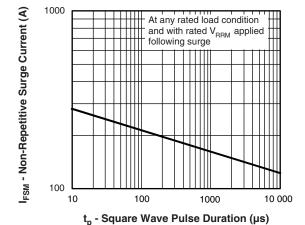


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

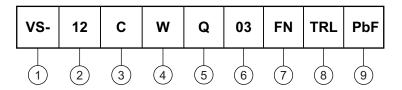


Schottky Rectifier, 2 x 6 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (12 A)

Center tap configuration

Package identifier:

W = D-PAK

5 - Schottky "Q" series

6 - Voltage rating (03 = 30 V)

7 - FN = TO-252AA

• None = Tube (50 pieces)

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

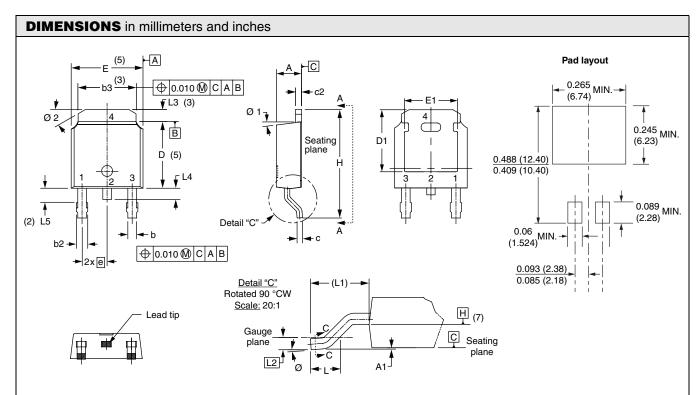
9 - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95016			
Part marking information	www.vishay.com/doc?95059			
Packaging information	www.vishay.com/doc?95033			



Vishay High Power Products

D-PAK (TO-252AA)



SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIM	MILLIMETERS		INCHES		
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
е	2.29	BSC	0.090	BSC		
Н	9.40	10.41	0.370	0.410		
L	1.40	1.78	0.055	0.070		
L1	2.74	2.74 BSC		0.108 REF.		
L2	0.51	BSC	0.020 BSC			
L3	0.89	1.27	0.035	0.050	3	
L4	-	1.02	-	0.040		
L5	1.14	1.52	0.045	0.060	2	
Ø	0°	10°	0°	10°		
Ø1	0°	15°	0°	15°		
Ø2	25°	35°	25°	35°		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- $^{(7)}$ Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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